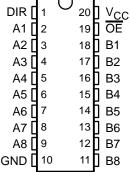
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- Controlled Baseline
 - One Assembly/Test Site, One Fabrication Site
- Extended Temperature Performance of -55°C to 125°C
- Enhanced Diminishing Manufacturing Sources (DMS) Support
- Enhanced Product-Change Notification
- Qualification Pedigree[†]
- Operating Range 2-V to 5.5-V V_{CC}
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds 1000 V Per MIL-STD-833, Method 3015; Exceeds 100 V Using Machine Model (C = 200 pF, R = 0)

† Component qualification in accordance with JEDEC and industry standards to ensure reliable operation over an extended temperature range. This includes, but is not limited to, Highly Accelerated Stress Test (HAST) or biased 85/85, temperature cycle, autoclave or unbiased HAST, electromigration, bond intermetallic life, and mold compound life. Such qualification testing should not be viewed as justifying use of this component beyond specified performance and environmental limits.

DW OR PW PACKAGE (TOP VIEW)



description/ordering information

The SN74AHC245 octal bus transceiver is designed for asynchronous two-way communication between data buses. The control-function implementation minimizes external timing requirements.

This device allows data transmission from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (\overline{OE}) input can be used to disable the device so that the buses effectively are isolated.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

ORDERING INFORMATION

TA	PAC	(AGE [‡]	ORDERABLE PART NUMBER	TOP-SIDE MARKING
–55°C to 125°C	SOIC - DW	Tape and reel	SN74AHC245MDWREP	AHC245MEP
-55°C 10 125°C	TSSOP – PW	Tape and reel	SN74AHC245MPWREP	AHC245EP

[‡] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



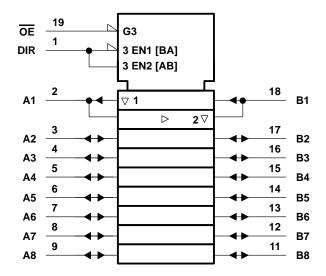
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FUNCTION TABLE (each transceiver)

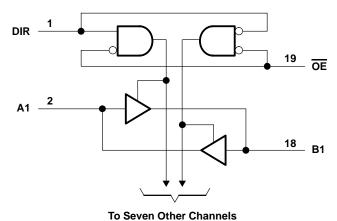
INP	UTS	ODEDATION				
OE	DIR	OPERATION				
L	L	B data to A bus				
L	Н	A data to B bus				
Н	X	Isolation				

logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)





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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	0.5 V to 7 V
Input voltage range, V _I (see Note 1): Control inputs	0.5 V to 7 V
I/O, output voltage range, V _O (see Note 1)	0.5 V to V _{CC} + 0.5 V
Input clamp current, I _{IK} (V _I < 0): Control inputs	–20 mA
I/O, output clamp current, I _{OK} (V _O < 0 or V _O > V _{CC})	±20 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})	±25 mA
Continuous current through V _{CC} or GND	±75 mA
Package thermal impedance, θ_{JA} (see Note 2): DW package	58°C/W
PW package	83°C/W
Storage temperature range, T _{stq}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions (see Note 3)

			MIN	MAX	UNIT
VCC	Supply voltage		2	5.5	V
	V _{CC} = 2 V		1.5		
V_{IH}	High-level input voltage	V _{CC} = 3 V	2.1		V
		$V_{CC} = 5.5 V$	3.85		
		V _{CC} = 2 V		0.5	
V_{IL}	Low-level input voltage V _{CC} = 3 V			0.9	V
		$V_{CC} = 5.5 \text{ V}$		1.65	
٧ _I	Input voltage	OE or DIR	0	5.5	V
۷o	Output voltage	A or B	0	VCC	V
		V _{CC} = 2 V		-50	μΑ
ІОН	High-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		-4	mA
		V_{CC} = 5 V \pm 0.5 V		-8	ША
		V _{CC} = 2 V		50	μΑ
loL	Low-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		4	m ^
		V_{CC} = 5 V \pm 0.5 V	8		mA
A+/A>.	Input transition rise or fall rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		100	no/\/
Δt/Δv	input transition rise of fail rate	$V_{CC} = 5 V \pm 0.5 V$		20	ns/V
TA	Operating free-air temperature		-55	125	°C

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^{2.} The package thermal impedance is calculated in accordance with JESD 51-7.

SN74AHC245-EP OCTAL BUS TRANSCEIVER WITH 3-STATE OUTPUTS

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	Vac	T	չ = 25°C	;	MIN	MAX	UNIT
	PARAMETER	TEST CONDITIONS	VCC	MIN	TYP	MAX	IVIIIV	WAA	UNIT
			2 V	1.9	2		1.9		
		I _{OH} = -50 μA	3 V	2.9	3		2.9		
Vон			4.5 V	4.4	4.5		4.4		V
		I _{OH} = -4 mA	3 V	2.58			2.48		
		I _{OH} = -8 mA	4.5 V	3.94			3.8		
			2 V			0.1		0.1	
		I _{OL} = 50 μA	3 V			0.1		0.1	V
VOL			4.5 V			0.1		0.1	
		I _{OL} = 4 mA	3 V			0.36		0.5	
		I _{OL} = 8 mA	4.5 V			0.36		0.5	
1.	A or B inputs	V. – F.F.V. or CND	5.5 V			±0.1		±1	
1 ₁	OE or DIR	V _I = 5.5 V or GND	0 V to 5.5 V			±0.1		±1	μΑ
l _{OZ} †		$V_O = V_{CC}$ or GND, $V_I (\overline{OE}) = V_{IL}$ or V_{IH}	5.5 V			±0.25		±2.5	μΑ
ICC		$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V	·		4		40	μΑ
Ci	OE or DIR	$V_I = V_{CC}$ or GND	5 V		2.5	10			pF
C _{io}	A or B inputs	V _I = V _{CC} or GND	5 V		4				pF

[†] The parameter IOZ includes the input leakage current.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	TΔ	= 25°C	;	MIN	MAX	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	IVIIIV	WIAA	ONII
^t PLH	A or B	B or A	C _I = 15 pF		5.8	8.4	1	10	nc
^t PHL	AUIB	B or A	CL = 15 pr		5.8	8.4	1	10	ns
^t PZH	ŌĒ	A or B	C: - 15 pF		8.5	13.2	1	15.5	20
^t PZL	OE	AUIB	C _L = 15 pF		8.5	13.2	1	15.5	ns
^t PHZ	ŌĒ	A or B	C _I = 15 pF		8.9	12.5	1	15.5	ns
^t PLZ	OE	AUIB	CL = 13 pr		8.9	12.5	1	15.5	113
^t PLH	A or B	B or A	C _L = 50 pF		8.3	11.9	1	13.5	nc
^t PHL	AUIB				8.3	11.9	1	13.5	ns
^t PZH	ŌĒ	A or B	C: - 50 pF		11	16.7	1	19	20
^t PZL	OE	AUID	C _L = 50 pF		11	16.7	1	19	ns
^t PHZ	ŌĒ	A or B	C: - F0 pF		11.5	15.8	1	18	no
t _{PLZ}	OE .	AUID	C _L = 50 pF		11.5	15.8	1	18	ns



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switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	T,	λ = 25°C	;	MIN	MAX	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	IVIIIV	WAX	UNIT
^t PLH	A or B	B or A	C _I = 15 pF		4	5.5	1	6.5	ns
^t PHL	AOIB	B or A	C[= 13 μ		4	5.5	1	6.5	115
^t PZH	ŌĒ	A or B	C _L = 15 pF		5.8	8.5	1	10	ns
^t PZL	OE	AUID	C[= 15 pr		5.8	8.5	1	10	110
^t PHZ	ŌĒ	A or B	C _I = 15 pF		5.6	7.8	1	9.2	ns
t _{PLZ}	OE	AUB	CL = 13 pr		5.6	7.8	1	9.2	113
^t PLH	A or B	B or A	C: 50 pF		5.5	7.5	1	8.5	ns
^t PHL	AOIB	BUIA	$C_L = 50 \text{ pF}$		5.5	7.5	1	8.5	115
^t PZH	ŌĒ	A or B	0 50 5		7.3	10.6	1	12	ns
^t PZL	OE .	AUID	C _L = 50 pF		7.3	10.6	1	12	115
^t PHZ	ŌĒ	A or B	C: - 50 pF		7	9.7	1	11	200
^t PLZ	OE	AUID	C _L = 50 pF		7	9.7	1	11	ns

noise characteristics, V_{CC} = 5 V, C_L = 50 pF, T_A = 25°C (see Note 4)

	PARAMETER	MIN	TYP	MAX	UNIT		
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		0.9		V		
V _{OL(V)}	Quiet output, minimum dynamic V _{OL} -0.9						
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}		4.3		V		
VIH(D)	High-level dynamic input voltage	3.5			V		
V _{IL(D)}	Low-level dynamic input voltage			1.5	V		

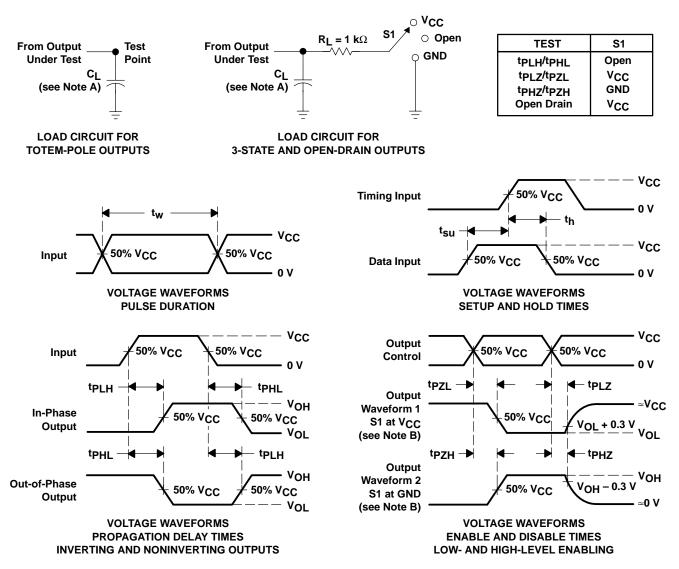
NOTE 4: Characteristics are for surface-mount packages only.

operating characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

	PARAMETER	TEST CONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	No load, f = 1 MHz	14	pF



PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_f \leq 3$ ns. $t_f \leq 3$ ns.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms





PACKAGE OPTION ADDENDUM

10-Dec-2020

PACKAGING INFORMATION

www.ti.com

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74AHC245MDWREP	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	AHC245MEP	Samples
SN74AHC245MPWREP	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	AHC245EP	Samples
V62/03650-01XE	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	AHC245EP	Samples
V62/03650-01YE	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	AHC245MEP	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN74AHC245-EP:

Catalog: SN74AHC245

Automotive: SN74AHC245-Q1

Military: SN54AHC245

NOTE: Qualified Version Definitions:

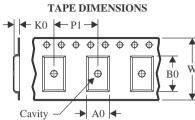
- Catalog TI's standard catalog product
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHC245MDWREP	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74AHC245MPWREP	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1

PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AHC245MDWREP	SOIC	DW	20	2000	367.0	367.0	45.0
SN74AHC245MPWREP	TSSOP	PW	20	2000	356.0	356.0	35.0

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